



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

N-Channel Junction Silicon FET

2SK3666 — Low-Frequency General-Purpose Amplifier, Impedance Converter Applications

Applications

- Low-frequency general-purpose amplifier, impedance conversion, infrared sensor applications

Features

- Small IGSS
- Small Ciss

Specifications

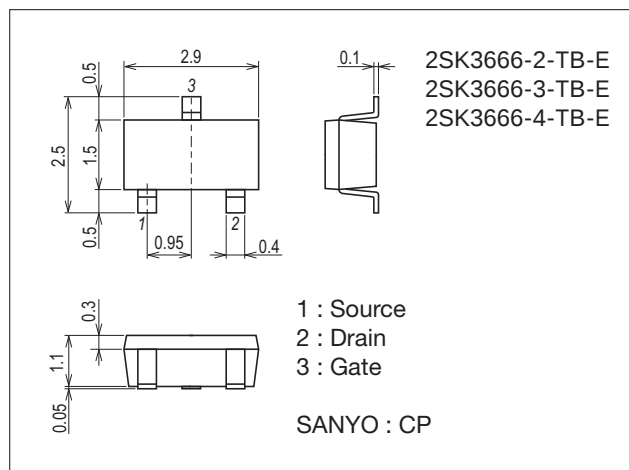
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSX}		30	V
Gate-to-Drain Voltage	V_{GDS}		-30	V
Gate Current	I_G		10	mA
Drain Current	I_D		10	mA
Allowable Power Dissipation	P_D		200	mW
Junction Temperature	T_J		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Package Dimensions

unit : mm (typ)

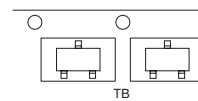
7013A-011



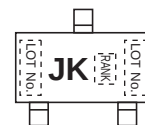
Product & Package Information

- Package : CP
- JEITA, JEDEC : SC-59, TO-236, SOT-23, TO-236AB
- Minimum Packing Quantity : 3,000 pcs./reel

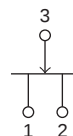
Packing Type: TL



Marking



Electrical Connection



SANYO Semiconductor Co., Ltd.

<http://semicon.sanyo.com/en/network>

Electrical Characteristics at Ta=25°C

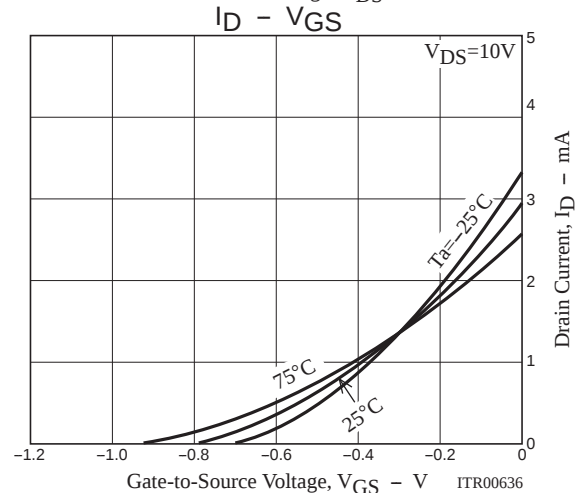
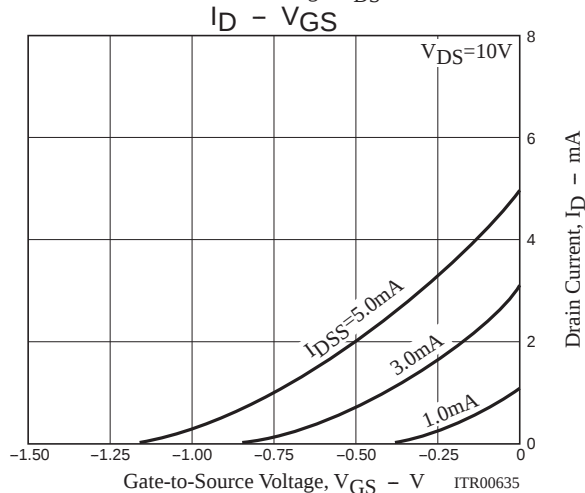
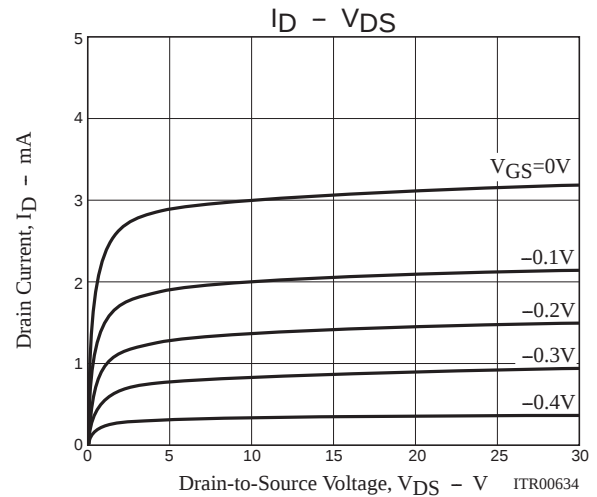
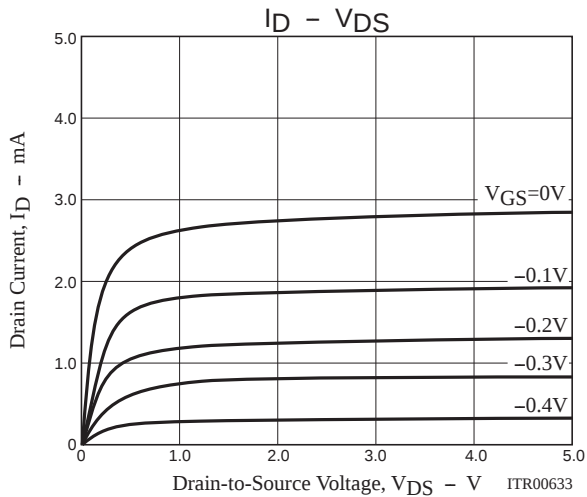
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Gate-to-Drain Breakdown Voltage	$V_{(BR)GDS}$	$I_G = -10\mu A$, $V_{DS} = 0V$	-30			V
Gate Cutoff Current	I_{GSS}	$V_{GS} = -20V$, $V_{DS} = 0V$			-1.0	nA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = 10V$, $I_D = 1\mu A$	-0.18	-0.95	-2.2	V
Drain Current	I_{DSS}	$V_{DS} = 10V$, $V_{GS} = 0V$	0.6*		6.0*	mA
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = 10V$, $V_{GS} = 0V$, $f = 1kHz$	3.0	6.5		mS
Input Capacitance	C_{iss}	$V_{DS} = 10V$, $V_{GS} = 0V$, $f = 1MHz$		4		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS} = 10V$, $V_{GS} = 0V$, $f = 1MHz$		1.1		pF
Static Drain-to-Source On-State Resistance	$R_{DS(on)}$	$V_{DS} = 10mV$, $V_{GS} = 10V$		200		Ω

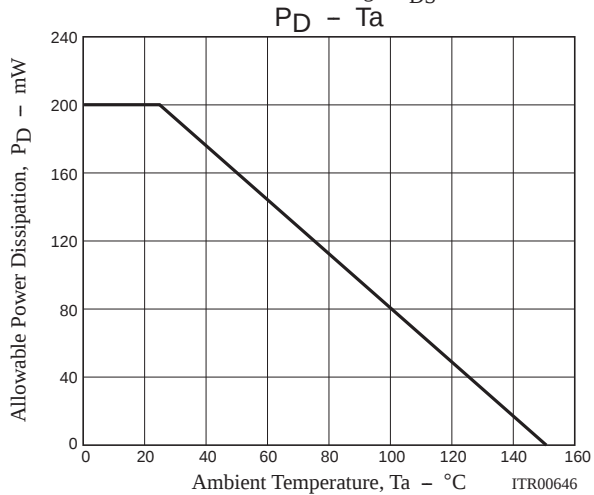
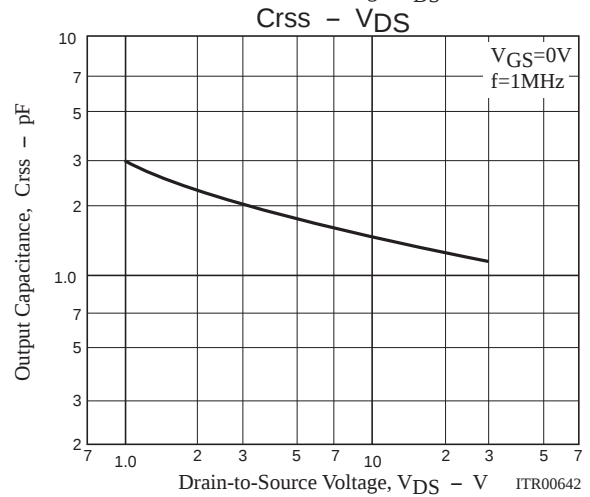
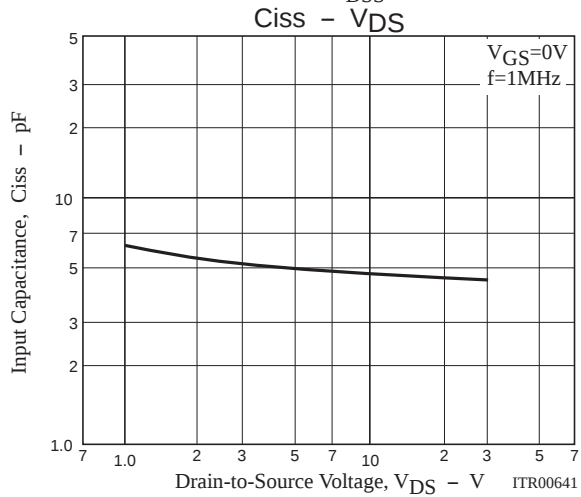
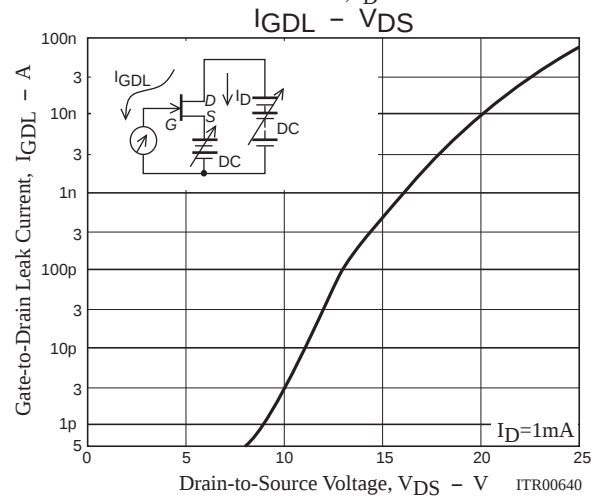
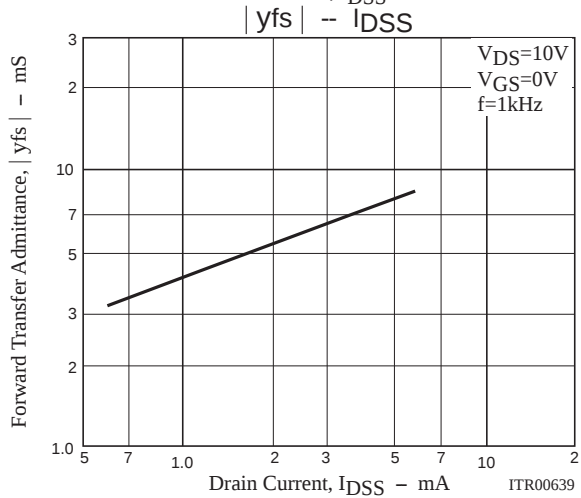
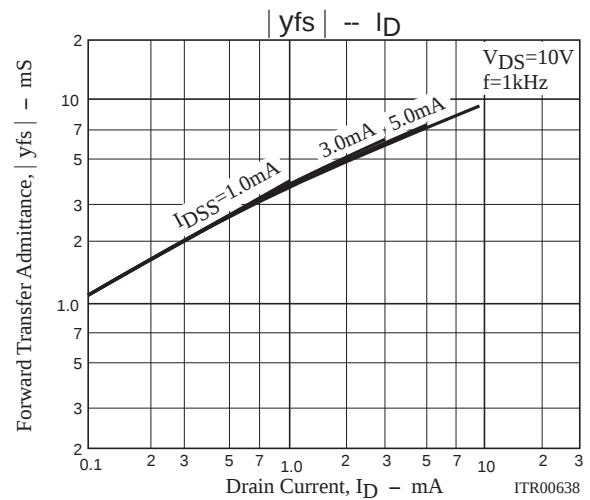
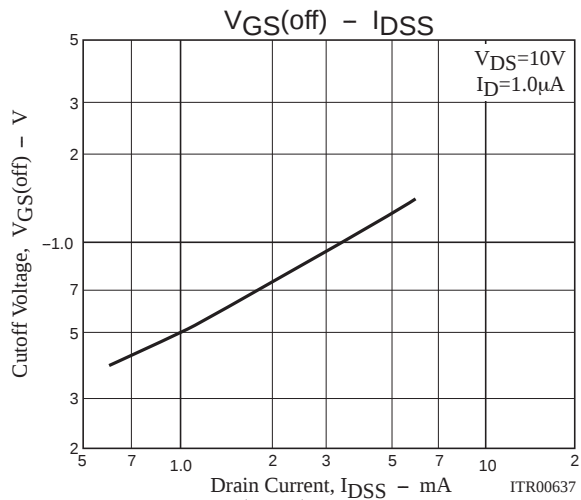
* : The 2SK3666 is classified by I_{DSS} as follows : (unit : mA)

Rank	2	3	4
I_{DSS}	0.6 to 1.5	1.2 to 3.0	2.5 to 6.0

Ordering Information

Device	Package	Shipping	memo
2SK3666-2-TB-E	CP	3,000pcs./reel	Pb Free
2SK3666-3-TB-E	CP	3,000pcs./reel	
2SK3666-4-TB-E	CP	3,000pcs./reel	





Embossed Taping Specification

2SK3666-2-TB-E, 2SK3666-3-TB-E, 2SK3666-4-TB-E

1. Packing Format

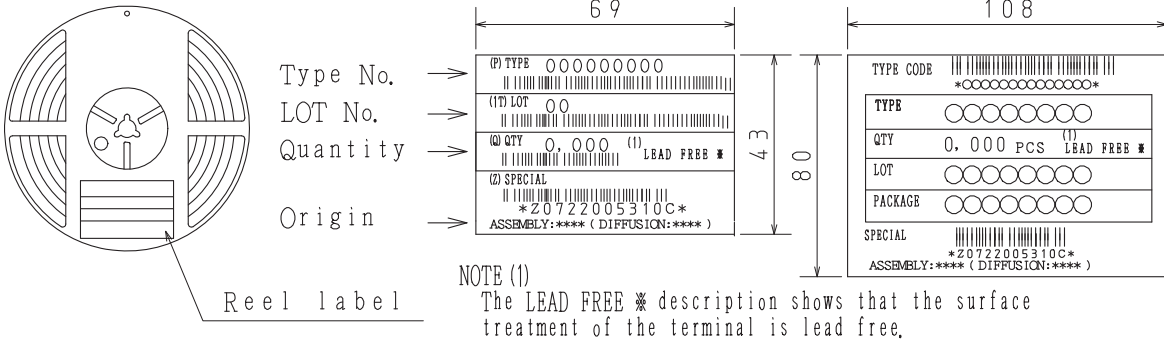
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CP	CP	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label
(unit:mm)

Outer box label

It is a label at the time of factory shipments.
The form of a label may change in physical
distribution process.

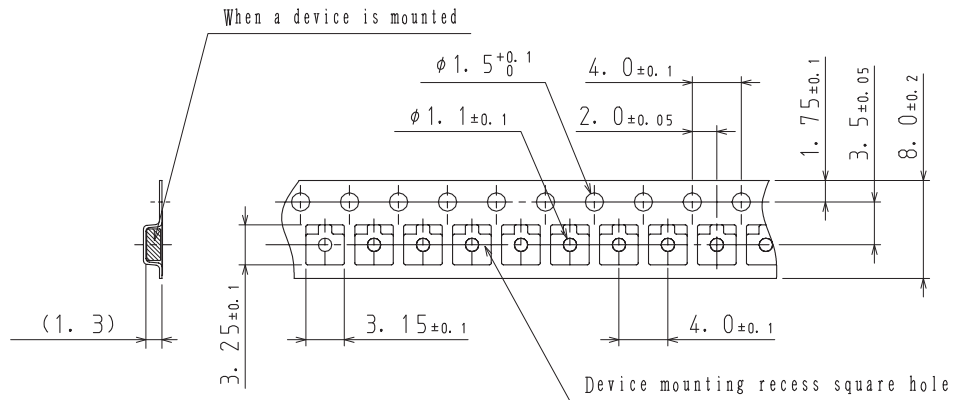
Packing method



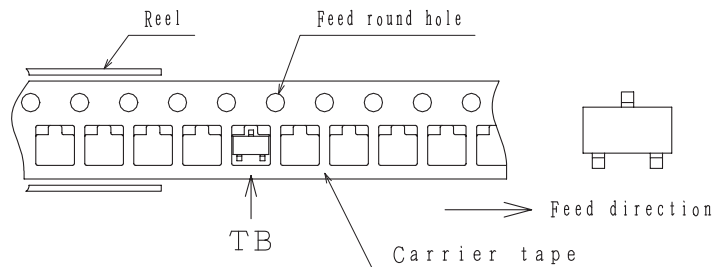
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



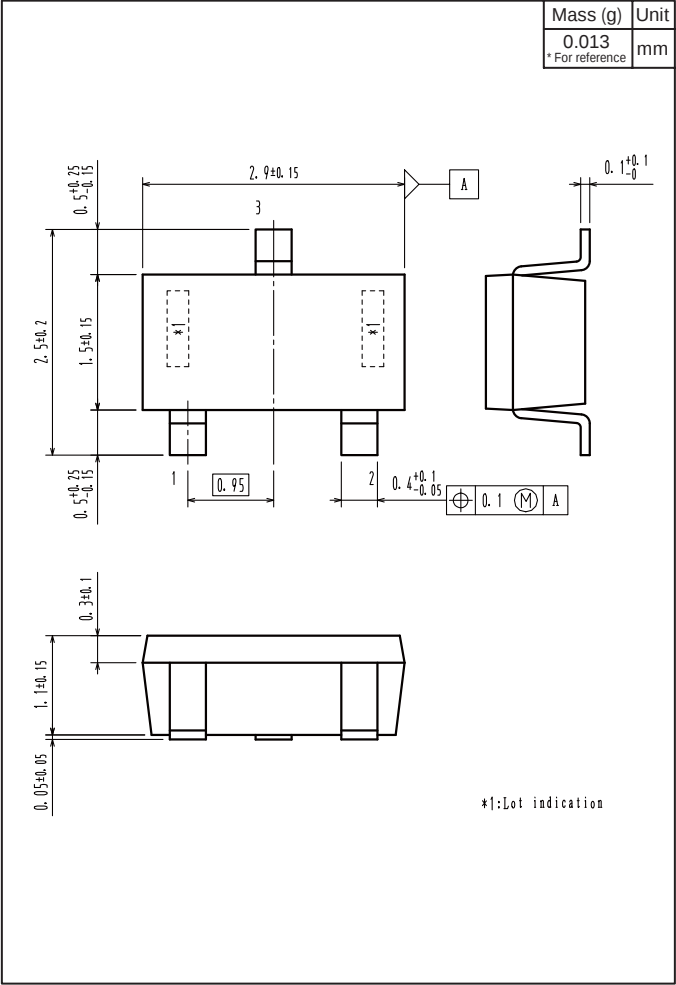
2-2. Device placement direction



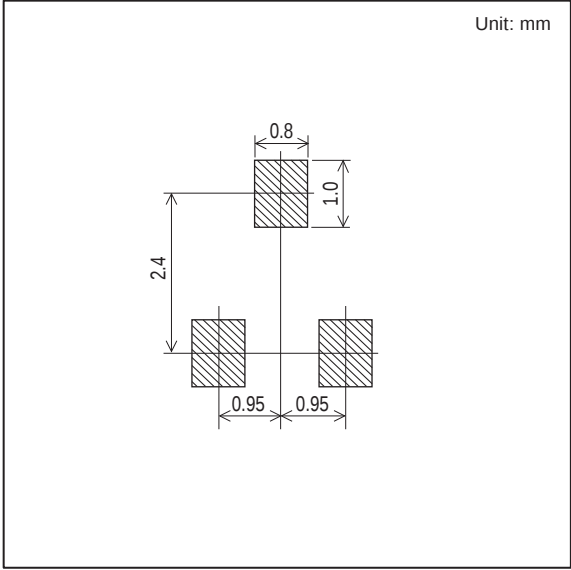
Those with one electrode terminal on the feed hole side.....TB

Outline Drawing

2SK3666-2-TB-E, 2SK3666-3-TB-E, 2SK3666-4-TB-E



Land Pattern Example



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